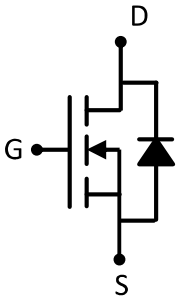
Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
100V	25mΩ@10V	40A
	38mΩ@4.5V	

TO252

Schematic diagram



Feature

- TrenchFET Power MOSFET
- Fast Switching
- Exceptional on-resistance and maximum DC current capability

Application

- DC/DC Converter
- Load Switch for Portable Devices
- Battery Switch

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP40N100K	AP40N100K	TO-252-3L		-	-

ABSOLUTE MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	+20/-12	V
Continuous Drain Current	I_D	40	A
Pulsed Drain Current	I_{DM}	150	A
Single pulse avalanche energy	EAS	95	mJ
Power Dissipation	P_D	40	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	3	℃/W
Junction Temperature	T_J	150	℃
Storage Temperature	T_{STG}	-55~ +150	℃

MOSFET ELECTRICAL CHARACTERISTICS(T_a=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D =-250μA	100			V
Zero gate voltage drain current	I_{DSS}	V_{DS} =100V, V_{GS} = 0V			1	μA
Gate-body leakage current	I_{GSS}	V_{GS} =+20V, V_{DS} = 0V			±100	nA
Gate threshold voltage(1)	$V_{GS(th)}$	V_{DS} =V_{GS}, I_D =-250μA	1	1.6	2.5	V
Drain-source on-resistance(1)	$R_{DS(on)}$	V_{GS} =10V, I_D =15A		20	25	mΩ
		V_{GS} =4.5V, I_D =10A		30	38	
Forward tranconductance(1)	g_{FS}	V_{DS} =10V, I_D =15A		10		S
Dynamic characteristics(2)						
Input Capacitance	C_{iss}	V_{DS} =50V, V_{GS} =0V, f =1MHz		1015		pF
Output Capacitance	C_{oss}			285		
Reverse Transfer Capacitance	C_{rss}			27		
Switching characteristics(2)						
Turn-on delay time	$t_{d(on)}$	V_{DD}=50V, I_D=1A, R_L=6Ω V_{GS}=10V, R_G=1Ω		10	20	ns
Turn-on rise time	t_r			13.5	27	
Turn-off delay time	$t_{d(off)}$			28	56	
Turn-off fall time	t_f			20	40	
Total Gate Charge	Qg	VDS=50V, ID=10A, VGS=10V		15	30	nC
Gate-Source Charge	Qgs			1.5		
Gate-Drain Charge	Qgd			4.2		
Source-Drain Diode characteristics						
Diode Forward voltage(1)	V_{DS}	V_{GS} =0V, I_S=1A			1	V

Notes:

1. Pulse test; pulse width≤300μs, duty cycle≤2%.
2. Guaranteed by design, not subject to production testing.

RATING AND CHARACTERISTICS CURVES

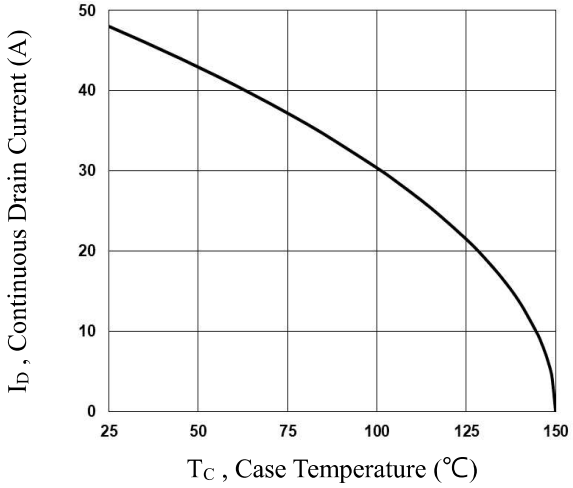


Fig.1 Continuous Drain Current vs. T_C

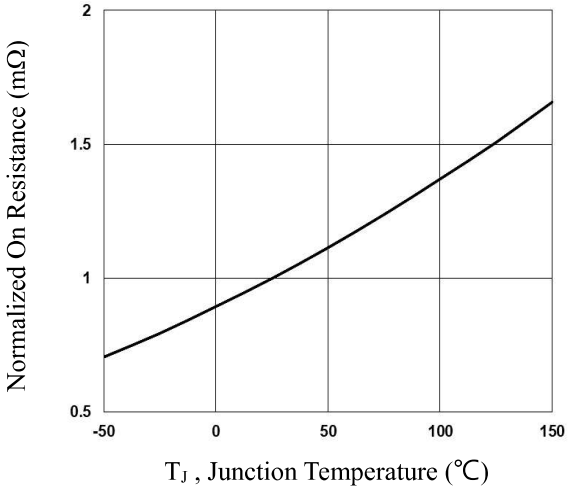


Fig.2 Normalized RDSON vs. T_J

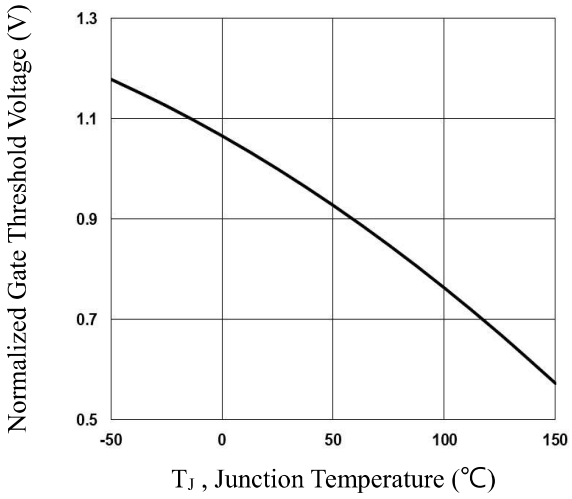


Fig.3 Normalized V_{th} vs. T_J

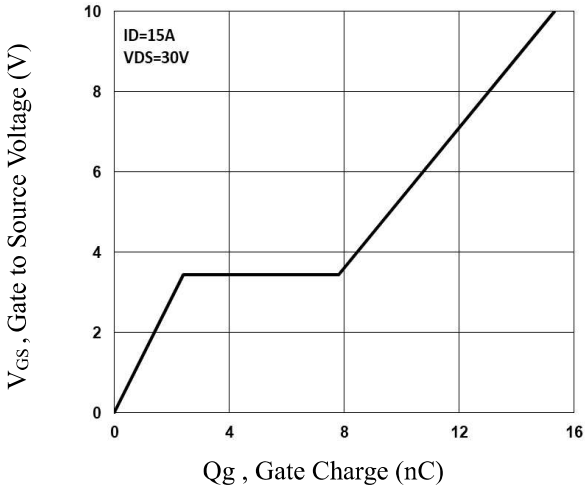


Fig.4 Gate Charge Waveform

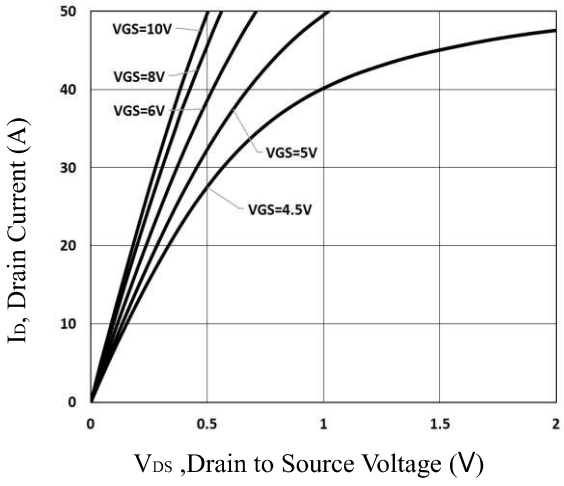


Fig.5 Typical Output Characteristics

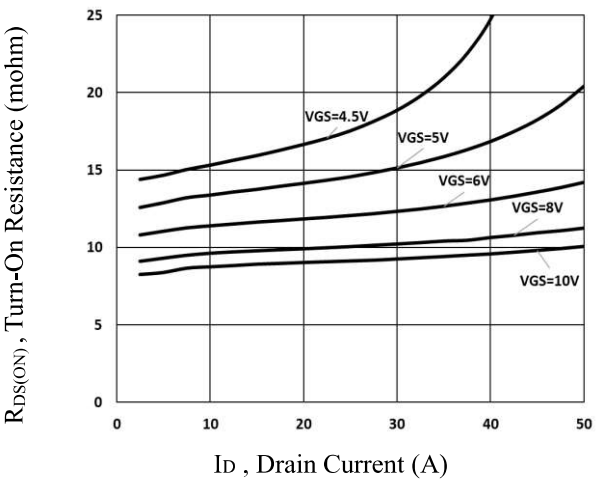


Fig.6 Turn-On Resistance vs. I_D

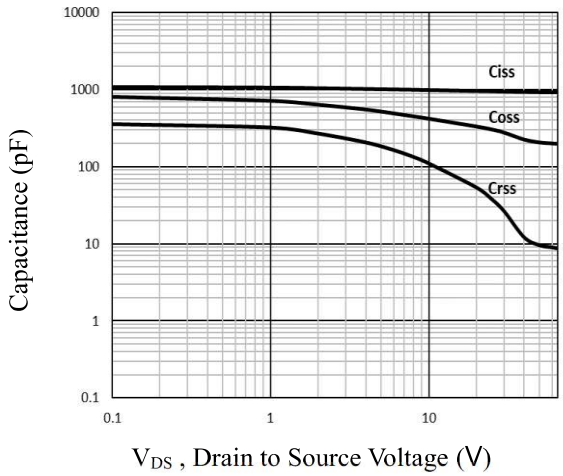


Fig.7 Capacitance Characteristics

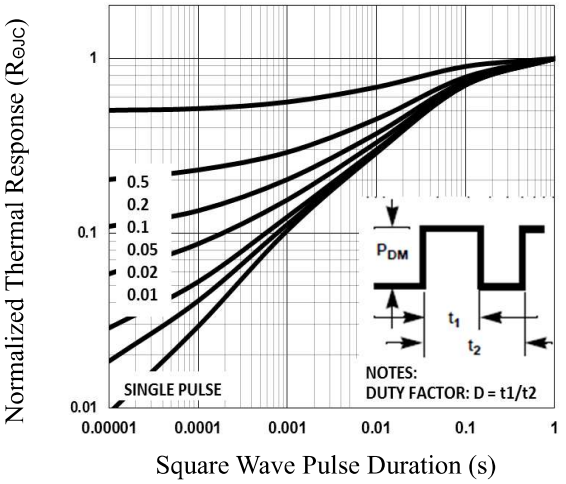


Fig.8 Normalized Transient Response

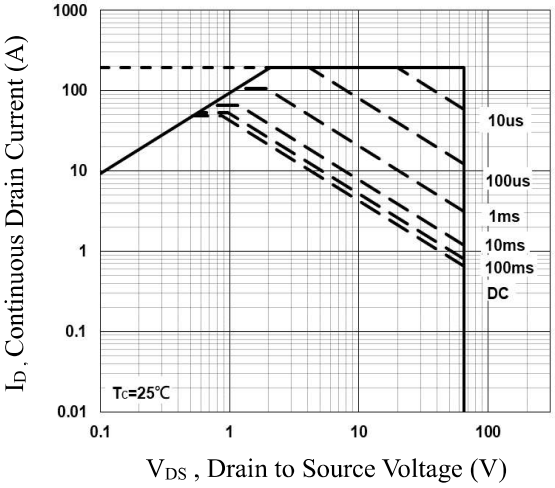


Fig.9 Maximum Safe Operation Area

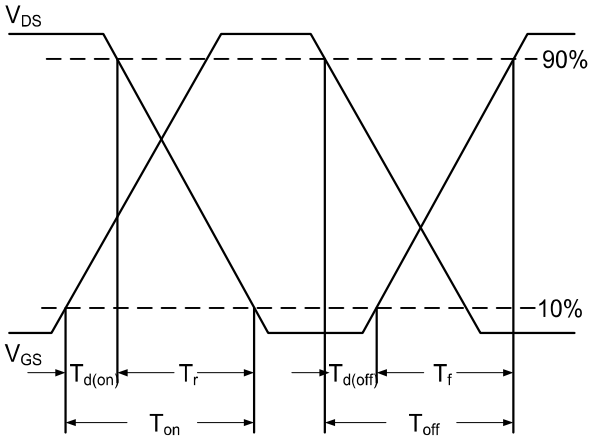


Fig.10 Switching Time Waveform

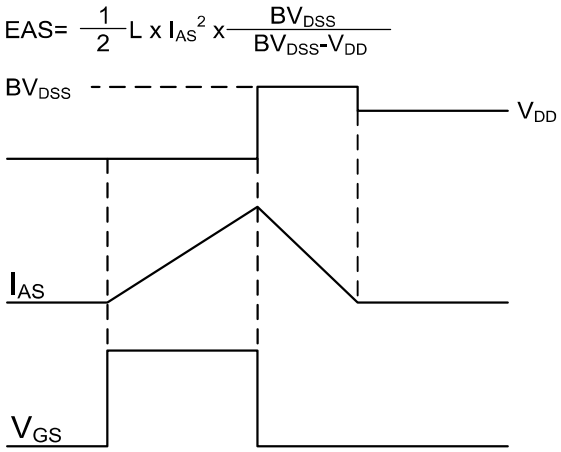
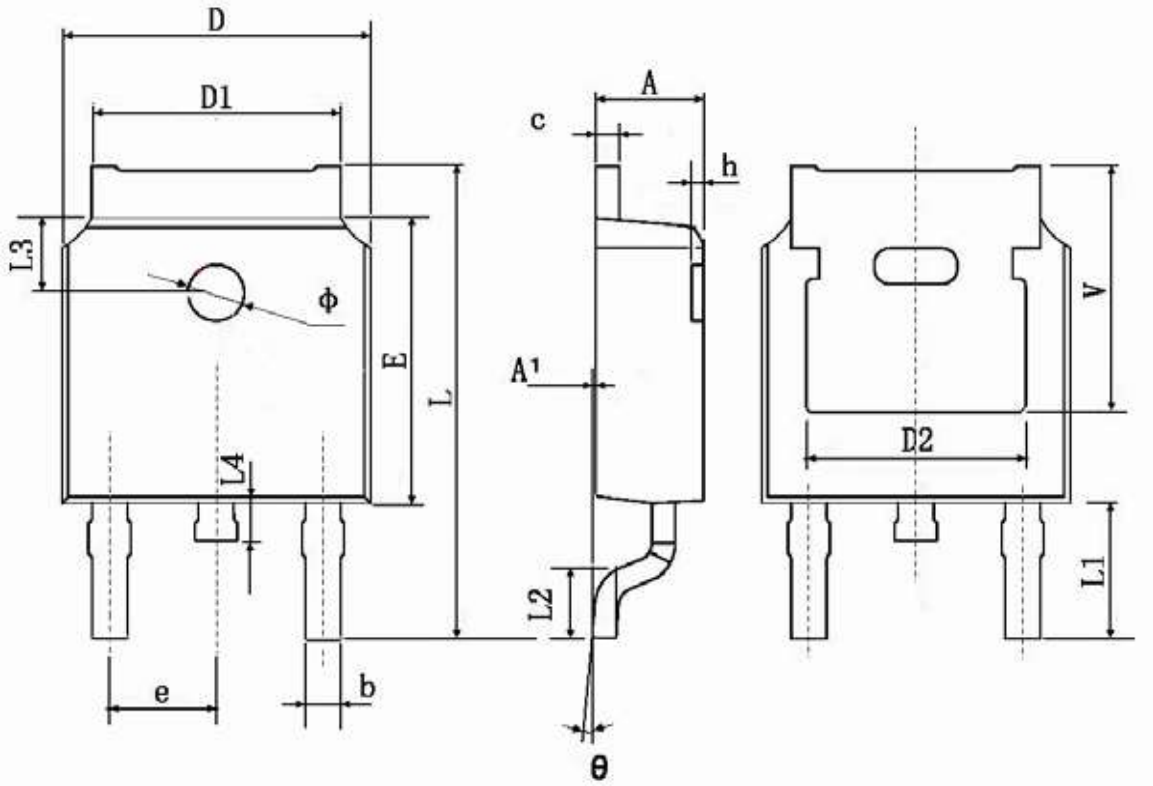


Fig.11 EAS Waveform

TO-252 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.660	0.860	0.026	0.034
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 TYP.		0.190 TYP.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 TYP.		0.114 TYP.	
L2	1.400	1.700	0.055	0.067
L3	1.600 TYP.		0.063 TYP.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.350 TYP.		0.211 TYP.	

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET ***category:***

Click to view products by Quan Li ***manufacturer:***

Other Similar products are found below :

614233C 648584F MCH3443-TL-E MCH6422-TL-E NTNS3A92PZT5G IRFD120 IRFF430 JANTX2N5237 2N7000 AOD464 2SK2267(Q) 2SK2545(Q,T) 405094E 423220D MIC4420CM-TR VN1206L 614234A 715780A SSM6J414TU,LF(T 751625C IPS70R2K0CEAKMA1 BSF024N03LT3 G PSMN4R2-30MLD TK31J60W5,S1VQ(O 2SK2614(TE16L1,Q) DMN1017UCP3-7 EFC2J004NUZTDG FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE2384 NTE2969 NTE6400A DMC2700UDMQ-7 DMN2080UCB4-7 DMN61D9UWQ-13 US6M2GTR DMN31D5UDJ-7 SSM6P54TU,LF DMP22D4UFO-7B IPS60R3K4CEAKMA1 DMN1006UCA6-7 DMN16M9UCA6-7 STF5N65M6 IRF40H233XTMA1 IPSA70R950CEAKMA1 IPSA70R2K0CEAKMA1 STU5N65M6 C3M0021120D DMN6022SSD-13